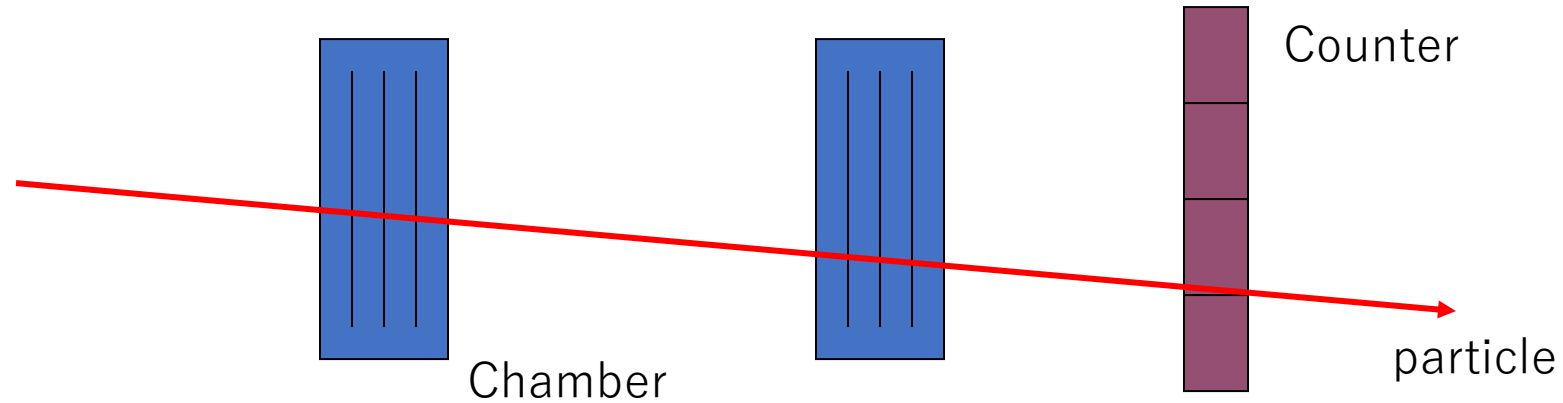


Monte Carlo ㇏ ㇏ 4

K. Miwa

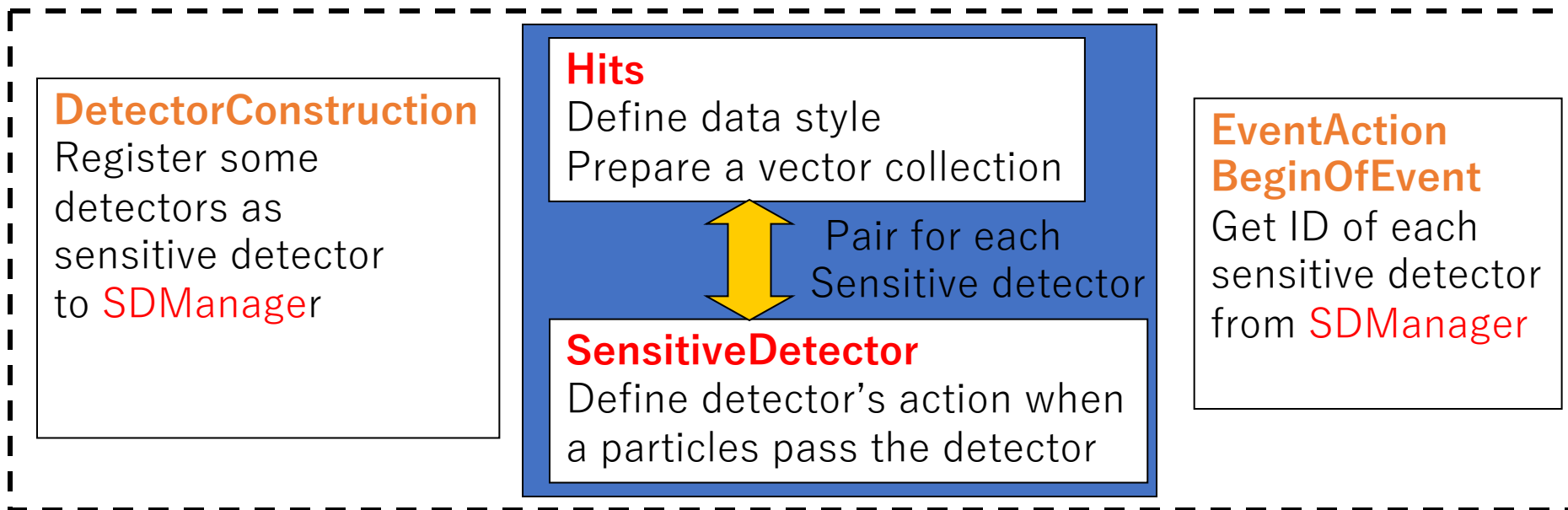
Sensitive detector



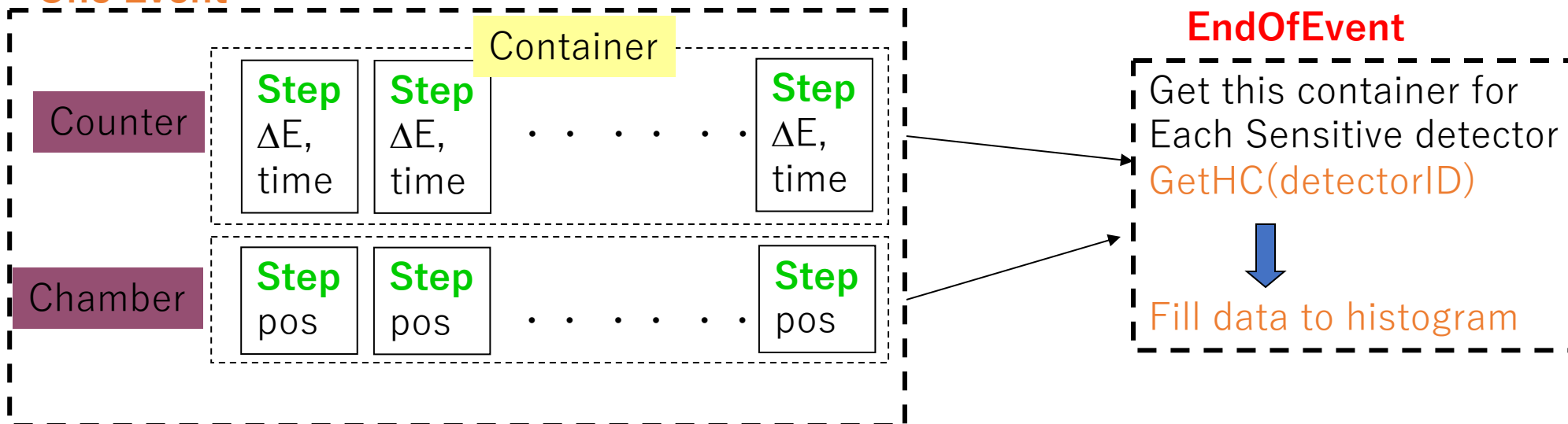
- In a simulation, we want to know
 - Position and time of the particle at the detector
 - Momentum and energy of the particle at the detector
 - Energy deposition of the particle in the detector
- We register the detector as a **sensitive detector**

Overview

Initialization



One Event



Registration of Sensitive Detector

DetectorConstruction.cc

```
solidCalor = new G4Box("Calorimeter", //its name
                      CalorThickness/2,CalorSizeYZ/2,CalorSizeYZ/2);

logicCalor = new G4LogicalVolume(solidCalor, //its solid
                                 Sci, //its material
                                 "Calorimeter"); //its name

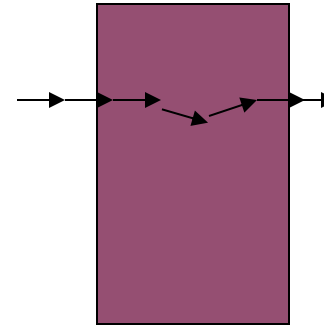
physiCalor = new G4PVPlacement(0, //no rotation
                               .....省略:)

//-----Sensitive Detector
G4SDManager* SDman = G4SDManager::GetSDMpointer();
if(!counterSD)
{
    counterSD = new ExN00CounterSD("counterSD",this);
    SDman->AddNewDetector( counterSD );
}
logicCalor->SetSensitiveDetector(counterSD);
```

G4SDManager is the singleton manager class for sensitive detector.
We register a sensitive detector to G4SDManager.

Hit

- A hit is a snapshot of the physical interaction of a track in the sensitive region.
- The information of
 - Position and time of the step
 - Momentum and energy of track
 - Energy deposition of the step
 - Geometrical information
- G4VHit
 - G4VHit is an abstract base class which represent a hit
 - You have to inherit this base class and derive your own class
- G4THitsCollection
 - There are many hits in one event.
 - This is a vector collection which contain all hits in one event



```

class ExN00CounterHit : public G4VHit
{
public:

    ExN00CounterHit();
    ~ExN00CounterHit();
    ...省略...
public:
    void AddAbs(G4double de, G4double dl) {EdepAbs += de; TrackLengthAbs += dl;};
    void SetTime(G4double time) {Time =time;};
    G4double GetEdepAbs()    { return EdepAbs; };
    G4double GetTrakAbs()    { return TrackLengthAbs; };
    G4double GetTime()      { return Time; };
private:
    G4double EdepAbs, TrackLengthAbs;
    G4double Time;
};

//...oooO0000ooo.....oooO0000ooo.....oooO0000ooo.....oooO0000ooo.....

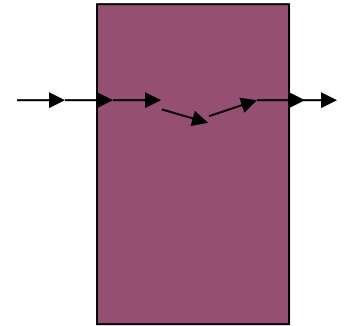
typedef G4THitsCollection<ExN00CounterHit> ExN00CounterHitsCollection;

extern G4Allocator<ExN00CounterHit> ExN00CounterHitAllocator;

```

Sensitive Detector

- G4VSensitiveDetector is an abstract base class which represents a detector. The principal mandate of a sensitive detector is the construction of hit objects using information from steps along a particle track.
- The ProcessHits() method performs this task using G4Step objects as input
- ProcessHits() method
 - This method is invoked when there is a step in the sensitive detector.
 - In this method, you can get information of the particle which pass the detector and energy deposit.
 - These values are passed to ***Hit class .
 - Then this Hit information are stored in a vector container.



```

G4bool ExN00CounterSD::ProcessHits(G4Step* aStep,G4TouchableHistory* ROhist)
{
  //G4cout << "####ExN00CalorimeterSD::ProcessHits " << detectorname << G4endl;
  G4double edep = aStep->GetTotalEnergyDeposit();
  G4double time = aStep->GetTrack()->GetGlobalTime();

  G4double stepl = 0.;
  G4String particleName;
  particleName = aStep->GetTrack()->GetDefinition()->GetParticleName();
  if (aStep->GetTrack()->GetDefinition()->GetPDGCharge() != 0.)
    stepl = aStep->GetStepLength();

  if ((edep==0.)&&(stepl==0.)) return false;

  G4TouchableHistory* theTouchable
    = (G4TouchableHistory*)(aStep->GetPreStepPoint()->GetTouchable());

  if (HitID==-1)
  {
    ExN00CounterHit* calHit = new ExN00CounterHit();
    calHit->AddAbs(edep, stepl);
    calHit->SetTime(time);
    HitID = CalCollection->insert(calHit) - 1;
  }
  else
  {
    (*CalCollection)[HitID]->AddAbs(edep,stepl);
  }

  return true;
}

```


EndOfEvent

```
void ExN00EventAction::EndOfEventAction(const G4Event*
evt)
{
    G4int evtNb = evt->GetEventID();

    G4HCofThisEvent* HCE = evt->GetHCofThisEvent();
    ExN00CounterHitsCollection* CounterHC = 0;

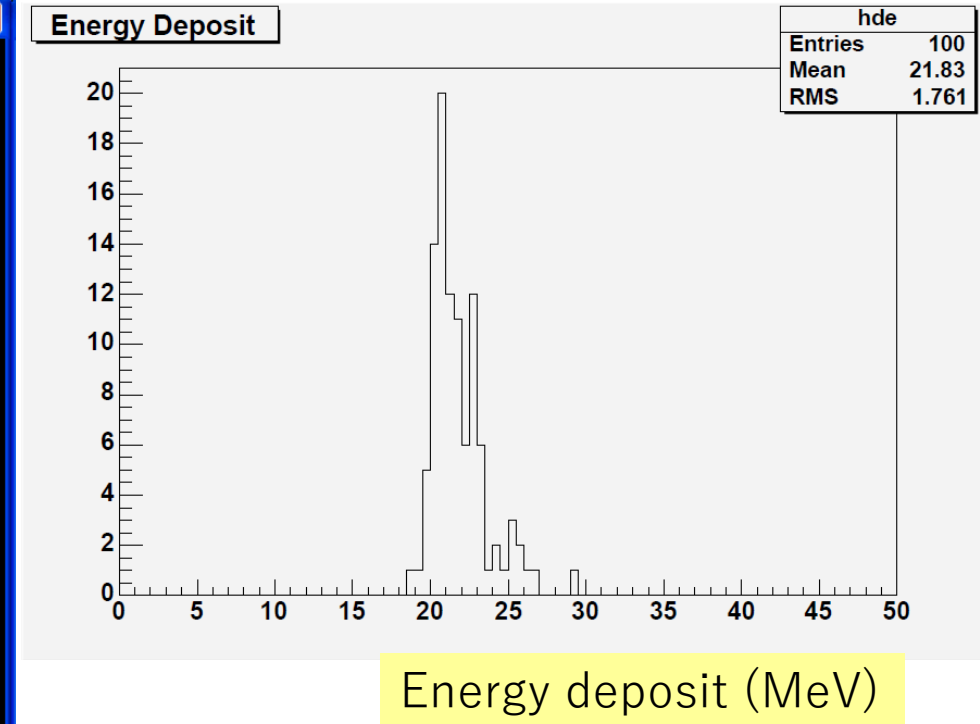
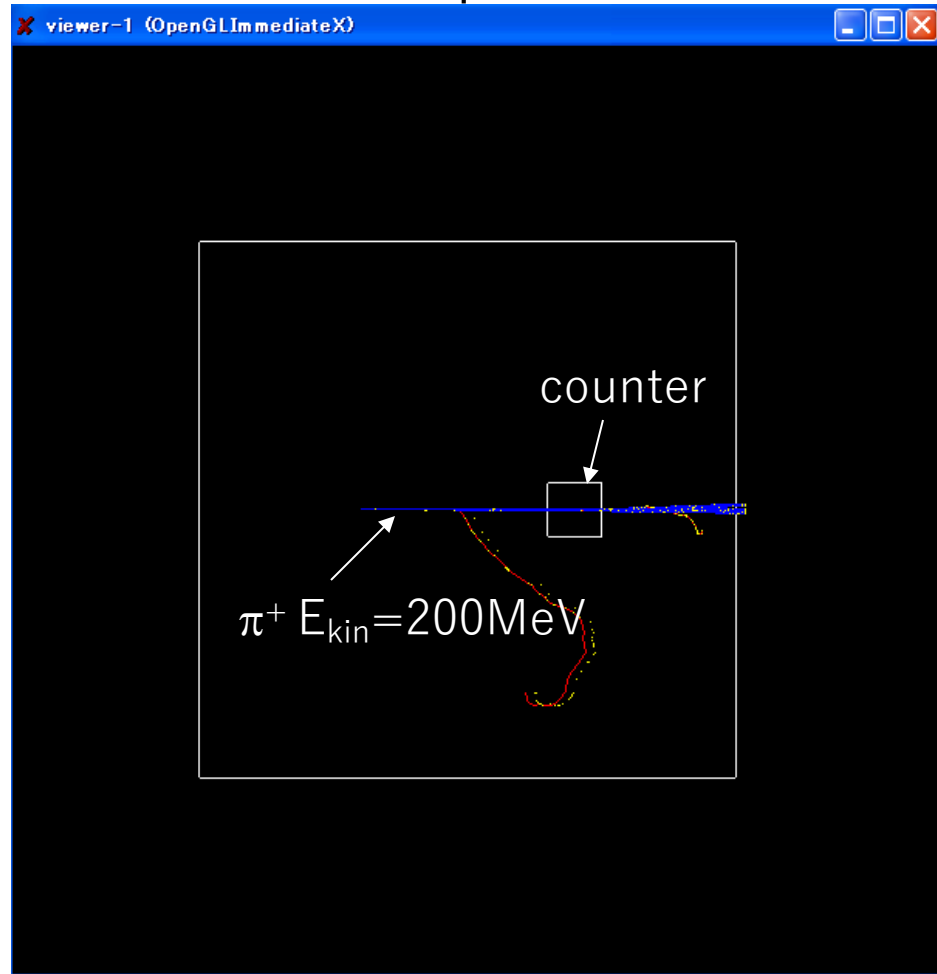
    if (HCE) CounterHC = (ExN00CounterHitsCollection*)(HCE-
>GetHC(counterCollID));
    if (CounterHC) {
        G4int n_hit = CounterHC->entries();
        for (G4int i=0;i<n_hit;i++){
            double time = (*CounterHC)[i]->GetTime();
            double de = (*CounterHC)[i]->GetEdepAbs();
            G4cout << "Time : " << time << ", dE : " << de <<
G4endl;
            AnaRoot->FillEnergyDeposit(de);
            AnaRoot->FillTime(time);
        }
    }
}
```

- You can get HitCollectoin of your sensitive detector for 1event at the EndOfEvent

Template example

- dhcp2576:/home/sks/user/miwa/MonteCarlo/geant4/N00
- New Added files
 - ExN00CounterHit.cc, .hh **define Hit class and HitCollection**
 - ExN00CounterSD.cc, .hh **define SensitiveDetector's behavior**
 - ExN00RunAction.cc, .hh **open root file at the BeginOfRun and close root file at the EndOfRun**
 - ExN00AnaRoot.cc, .hh **define root files and histogram**
- Modified files
 - ExN00DetectorConstruction.cc, .hh
 - ExN00EventAction.cc, .hh
 - exampleN00.cc

Energy deposit at Counter (10cm thick plastic scintillator)



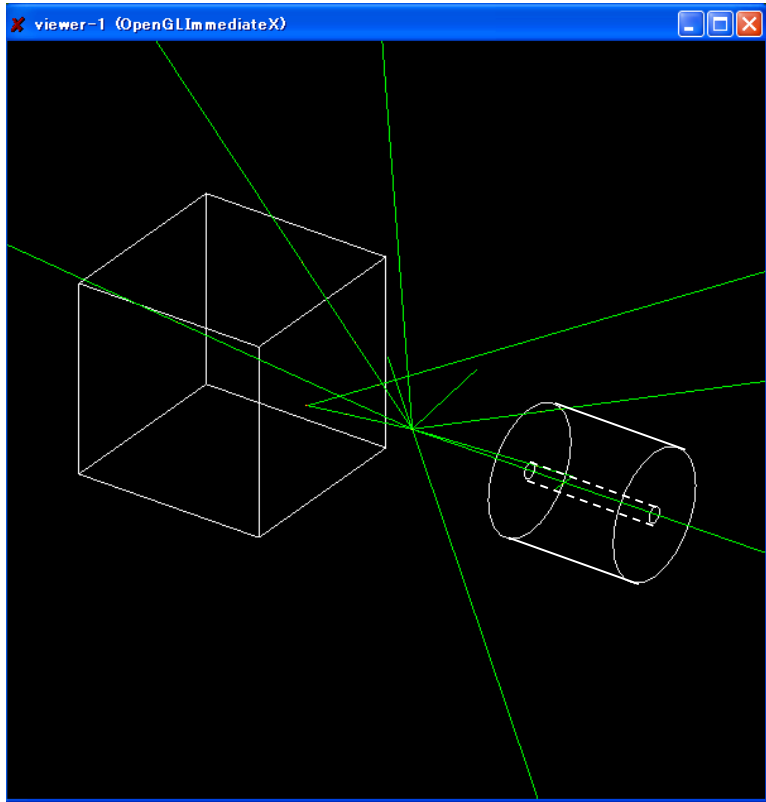
In this program, a root file is created for each run. (run(run#).root)

Practice

- 今の条件(π^+ , $E_{\text{kin}}=200\text{MeV}$, 10cm thick Scintillator)
 - Geantでenergy lossのヒストを作る。
 - Bethe-Blochで計算した値と比較する。
- カウンターの材質を鉛にする。このときに上の条件で行うとそれぞれどうなるか？ π^+ は鉛の中で止まるかどうか？
- $E_{\text{kin}}=200\text{MeV}$ の π^+ をscintillatorで止めるには厚さはどれくらい必要か？ Geantでシンチの厚さを変えながら調べてみる。
- シンチで π^+ を止めたとき、止まった場所の分布はどうなっているか？ このときは簡単のためdecay processはなしにしましょう。

Practice1:

Interaction of photon with materials



- Detector
 - Plastic scintillator
 - Position $(x, y, z) = (-10\text{cm}, 0, 0)$
 - Volume $10.\text{cm} \times 10.\text{cm} \times 10.\text{cm}$
 - Density 1.032 g/cm^3
 - Ge crystal
 - Position $(x, y, z) = (10\text{cm}, 0, 0)$
 - Volume $R_{\min} = 0.4\text{cm}, R_{\max} = 3.25\text{cm}, Z/2 = 3.47\text{cm}$
- Physics
 - Transportation
 - EMProcess
 - Decay process
- Primary Generation
 - Generate γ ray from $(0, 0, 0)$ isotropically in 3D space
 - $E_{\gamma} = 1\text{MeV}$
- Sensitive Detector
 - Plastic scintillator, Ge crystal
 - Measure energy deposit.
- Show energy deposit spectra of each detector.
- Compare the ratio of Compton scattering and photo electric effect ($\sigma_{\text{Compton}} \propto Z, \sigma_{\text{photo}} \propto Z^5$)

Practice2:

$\Delta E, E$ counter (particle identification)

- When you measure ΔE and total kinetic energy, you can identify the particle
 - ΔE depends on β
 - $E_{\text{Kin}} = \frac{1}{2} mv^2$
- Detector
 - Thin counter (Plastic scintillator)
 - Position $(x, y, z) = (2.5\text{cm}, 0, 0)$
 - Volume $10\text{cm}(W) \times 10\text{cm}(H) \times 1\text{cm}(T)$
 - Thick counter (Plastic scintillator)
 - Position $(x, y, z) = (25\text{cm}, 0, 0)$
 - Volume $10\text{cm}(W) \times 10\text{cm}(H) \times 40\text{cm}(T)$
- Physics process (**Do Not include decay**)
 - Transportation
 - EMProcess
- Primary Generation
 - Generate π^+, K^+, p in order
 - $E_{\text{kin}} 20\text{MeV} \sim 400\text{MeV}$
 - Beam direction $(1, 0, 0)$
- Sensitive Detector
 - Thin counter
 - Thick counter
- **Make a scattering plot (2-dim histogram) between ΔE (thin counter) and total E (thick counter)**

